

Product data sheet

1. General description

AC Thyristor power switch in a SOT223 surface-mountable plastic package with self-protective capabilities against low and high energy transients

2. Features and benefits

- Common terminal on mounting base allows multiple ACTs on shared cooling pad
- Exclusive negative gate triggering
- Full cycle AC conduction
- Remote gate separates the gate driver from the effects of the load current
- Surface-mountable package
- Very high noise immunity
- Safe clamping of low energy over-voltage transients
- Self-protective turn-on during high energy voltage transients

3. Applications

- · Contactors, circuit breakers, valves, dispensers and door locks
- Fan motor circuits
- Lower-power highly inductive, resistive and safety loads
- Pump motor circuits

4. Quick reference data

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Table 1. Quick	reference data					
Symbol	Parameter	Conditions	Mi	n Typ	Max	Unit
V _{DRM}	repetitive peak off- state voltage		-	-	600	V
I _{T(RMS)}	RMS on-state current	full sine wave; $T_{sp} \le 112 \text{ °C}$; Fig. 1; Fig. 2; Fig. 3	-	-	0.8	A
I _{TSM}	non-repetitive peak on- state current	full sine wave; T _{j(init)} = 25 °C; t _p = 16.7 ms	-	-	8.8	A
		full sine wave; T _{j(init)} = 25 °C; t _p = 20 ms; <u>Fig. 4; Fig. 5</u>	-	-	8	A
Tj	junction temperature		-	-	125	°C
V _{PP}	peak pulse voltage	T _j = 25 °C; non-repetitive, off-state; <u>Fig. 6</u>	-	-	2	kV
Static charac	teristics					
I _{GT}	gate trigger current	V _D = 12 V; I _T = 100 mA; LD+ G-; T _j = 25 °C; <u>Fig. 10</u>	1	-	10	mA

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Symbol	Parameter	Conditions	Min	Тур	Max	Unit
		V _D = 12 V; I _T = 100 mA; LD- G-; T _j = 25 °C	1	-	10	mA
I _H	holding current	V _D = 12 V; T _j = 25 °C; <u>Fig. 12</u>	-	9	25	mA
V _T	on-state voltage	I _T = 1.1 A; <u>Fig. 13</u>	-	-	1.3	V
V _{CL}	clamping voltage	I _{CL} = 100 μA; t _p = 1 ms; T _j = 125 °C; Fig. 14	650	-	-	V
Dynamic char	acteristics					
dV _D /dt	rate of rise of off-state voltage	V _{DM} = 402 V; T _j = 125 °C; gate open circuit; <u>Fig. 15</u>	1000	-	-	V/µs
dl _{com} /dt	rate of change of commutating current	V_D = 400 V; T _j = 125 °C; I _{T(RMS)} = 1 A; dV _{com} /dt = 15 V/µs; gate open circuit; Fig. 16; Fig. 17	0.3	-	-	A/ms

5. Pinning information

Table 2.	Pinning in	formation		
Pin	Symbol	Description	Simplified outline	Graphic symbol
1	LD	load	4	LD
2	СМ	common		
3	G	gate		G─ o ∏∠
4	СМ	common	∐1 ∐2 ∐3 SC-73 (SOT223)	CM 001aaj924

6. Ordering information

Table 3. Ordering information

Type number	Package				
	Name	Description	Version		
ACT108W-600E	SC-73	plastic surface-mounted package with increased heatsink; 4 leads	SOT223		

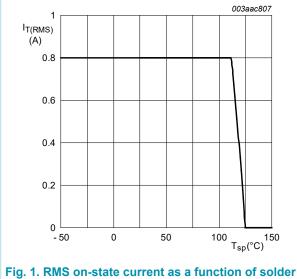


7. Limiting values

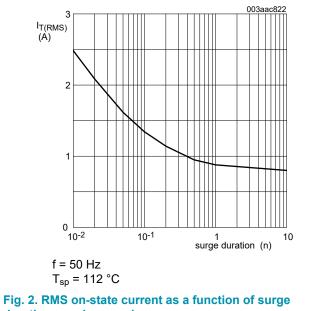
Table 4. Limiting values

In accordance with the Absolute Maximum Rating System (IEC 60134).

Symbol	Parameter	Conditions	Min	Max	Unit
V _{DRM}	repetitive peak off-state voltage		-	600	V
I _{T(RMS)}	RMS on-state current	full sine wave; $T_{sp} \le 112 \text{ °C}$; Fig. 1; Fig. 2; Fig. 3	-	0.8	A
I _{TSM}	non-repetitive peak on-	full sine wave; $T_{j(init)}$ = 25 °C; t_p = 16.7 ms	-	8.8	А
	state current	full sine wave; $T_{j(init)}$ = 25 °C; t_p = 20 ms; Fig. 4; Fig. 5	-	8	A
l ² t	I ² t for fusing	t _p = 10 ms; SIN	-	0.32	A²s
dl _T /dt	rate of rise of on-state current	I _G = 20 mA	-	100	A/µs
I _{GM}	peak gate current	t = 20 µs	-	1	А
V _{GM}	peak gate voltage	positive applied gate voltage	-	15	V
P _{G(AV)}	average gate power	over any 20 ms period	-	0.1	W
T _{stg}	storage temperature		-40	150	°C
Tj	junction temperature		-	125	°C
V _{PP}	peak pulse voltage	T _j = 25 °C; non-repetitive, off-state; <u>Fig. 6</u>	-	2	kV

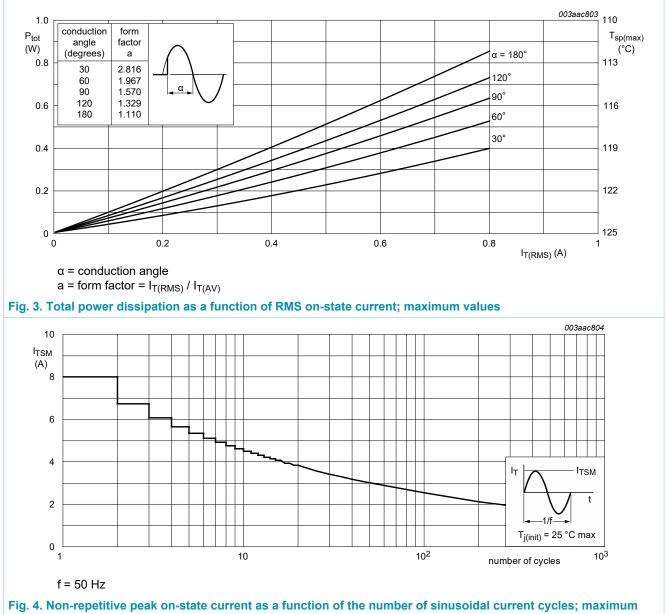


point temperature; maximum values



duration; maximum values

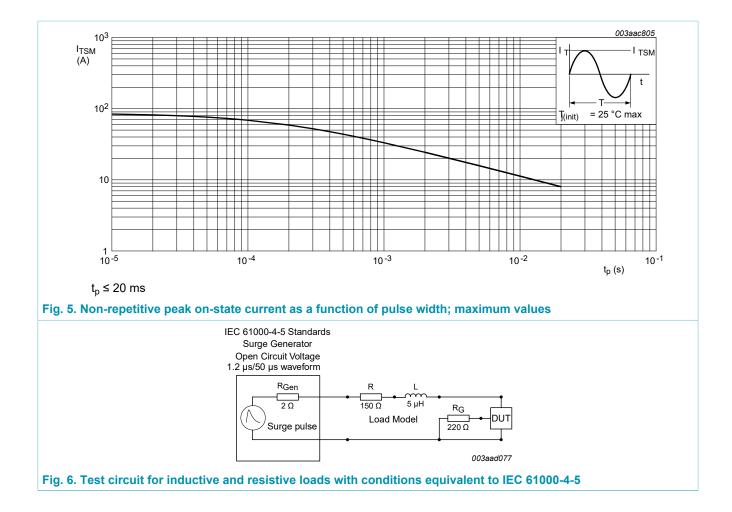
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values

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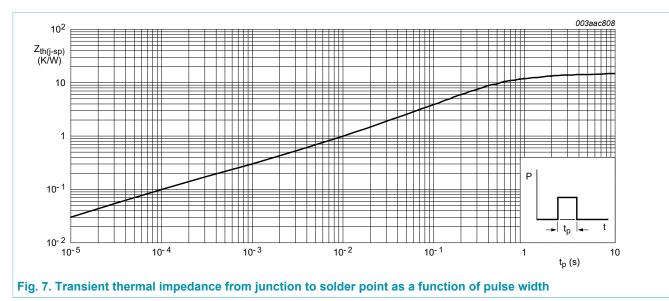




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8. Thermal characteristics

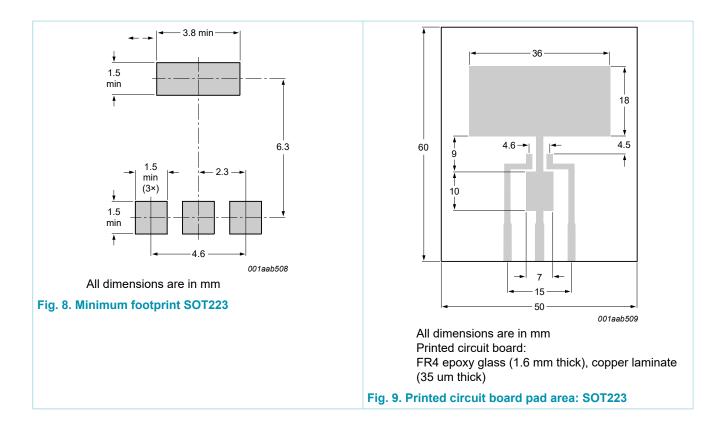
Symbol	Parameter	Conditions	Min	Тур	Max	Unit
R _{th(j-sp)}	thermal resistance from junction to solder point	full cycle with heatsink compound; Fig. 7	-	-	15	K/W
R _{th(j-a)}	thermal resistance from junction to ambient free air	in free air; printed circuit board mounted; minimum footprint; <u>Fig. 8</u>	-	156	-	K/W
		in free air; printed circuit board mounted; pad area; <u>Fig. 9</u>	-	70	-	K/W



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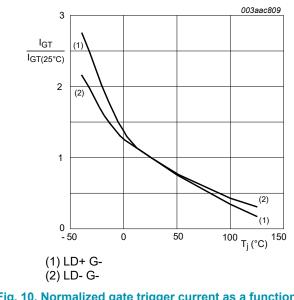
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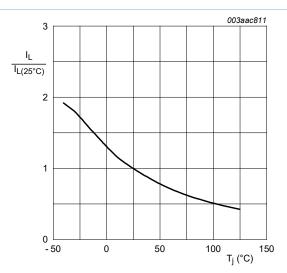
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9. Characteristics

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
Static chara	acteristics					
I _{GT}	gate trigger current	V _D = 12 V; I _T = 100 mA; LD+ G-; T _j = 25 °C; <u>Fig. 10</u>	1	-	10	mA
		V_D = 12 V; I _T = 100 mA; LD- G-; T _j = 25 °C	1	-	10	mA
IL	latching current	V _D = 12 V; I _G = 12 mA; T _j = 25 °C; <u>Fig. 11</u>	-	-	30	mA
I _H	holding current	V _D = 12 V; T _j = 25 °C; <u>Fig. 12</u>	-	9	25	mA
V _T	on-state voltage	I _T = 1.1 A; <u>Fig. 13</u>	-	-	1.3	V
V _{GT}	gate trigger voltage	V _D = 12 V; I _T = 100 mA; T _j = 125 °C	0.15	-	-	V
		V _D = 12 V; I _T = 100 mA; T _j = 25 °C	-	-	1	V
I _D	off-state current	V _D = 600 V; T _j = 125 °C	-	-	0.2	mA
		V _D = 600 V; T _j = 25 °C	-	-	2	μA
V _{CL}	clamping voltage	I _{CL} = 100 μA; t _p = 1 ms; T _j = 125 °C; <u>Fig. 14</u>	650	-	-	V
Dynamic ch	naracteristics	· · · ·				
dV _D /dt	rate of rise of off-state voltage	V _{DM} = 402 V; T _j = 125 °C; gate open circuit; <u>Fig. 15</u>	1000	-	-	V/µs
dI _{com} /dt	rate of change of commutating current	V _D = 400 V; T _j = 125 °C; I _{T(RMS)} = 1 A; dV _{com} /dt = 15 V/µs; gate open circuit; Fig. 16; Fig. 17	0.3	-	-	A/ms



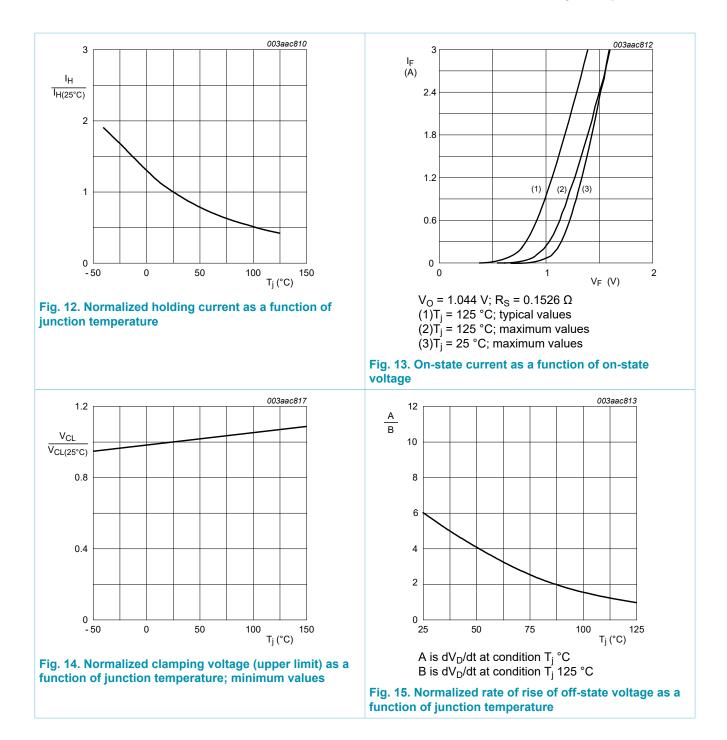






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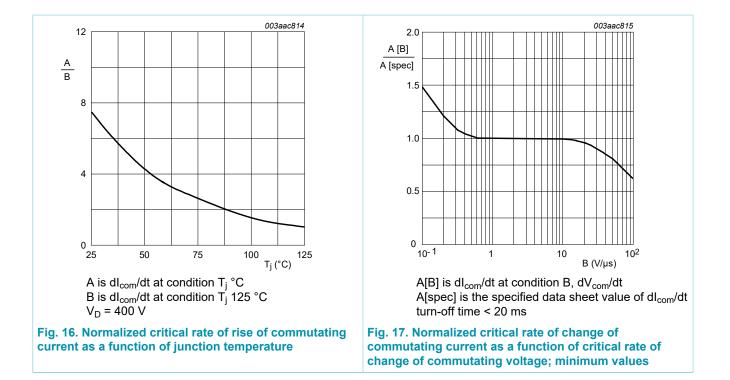
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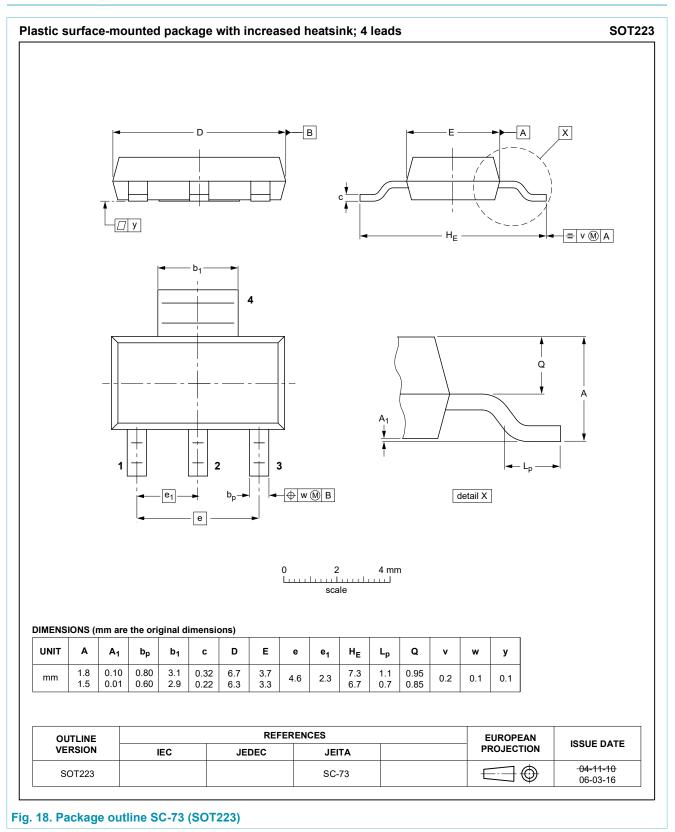


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10. Package outline



ACT108W-600E

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11. Legal information

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Document status [1][2]	Product status [<u>3]</u>	Definition
Objective [short] data sheet	Development	This document contains data from the objective specification for product development.
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Product [short] data sheet	Production	This document contains the product specification.

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